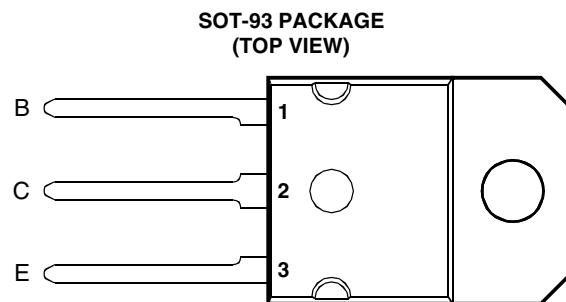


- Rugged Triple-Diffused Planar Construction
- 4 A Continuous Collector Current
- Operating Characteristics Fully Guaranteed at 100°C
- 1000 Volt Blocking Capability
- 100 W at 25°C Case Temperature



Pin 2 is in electrical contact with the mounting base.

MDTRAAA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ($I_E = 0$)	TIPL761 TIPL761A	V_{CBO}	850 1000	V
Collector-emitter voltage ($V_{BE} = 0$)	TIPL761 TIPL761A	V_{CES}	850 1000	V
Collector-emitter voltage ($I_B = 0$)	TIPL761 TIPL761A	V_{CEO}	400 450	V
Emitter-base voltage		V_{EBO}	10	V
Continuous collector current		I_C	4	A
Peak collector current (see Note 1)		I_{CM}	8	A
Continuous device dissipation at (or below) 25°C case temperature		P_{tot}	100	W
Operating junction temperature range		T_j	-65 to +150	°C
Storage temperature range		T_{stg}	-65 to +150	°C

NOTE 1: This value applies for $t_p \leq 10$ ms, duty cycle $\leq 2\%$.

PRODUCT INFORMATION

electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS				MIN	TYP	MAX	UNIT
$V_{CEO(sus)}$	$I_C = 10 \text{ mA}$	$L = 25 \text{ mH}$	(see Note 2)	TIPL761 TIPL761A	400 450			V
I_{CES}	$V_{CE} = 850 \text{ V}$ $V_{CE} = 1000 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$		TIPL761 TIPL761A		50 50	200 200	μA
I_{CEO}	$V_{CE} = 850 \text{ V}$ $V_{CE} = 1000 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$	$T_C = 100^\circ\text{C}$ $T_C = 100^\circ\text{C}$	TIPL761 TIPL761A			50 50	μA
I_{EBO}	$V_{EB} = 10 \text{ V}$	$I_C = 0$					1	mA
h_{FE}	$V_{CE} = 5 \text{ V}$	$I_C = 0.5 \text{ A}$	(see Notes 3 and 4)		20		60	
$V_{CE(sat)}$	$I_B = 0.5 \text{ A}$ $I_B = 0.8 \text{ A}$ $I_B = 0.8 \text{ A}$	$I_C = 2.5 \text{ A}$ $I_C = 4 \text{ A}$ $I_C = 4 \text{ A}$	(see Notes 3 and 4) $T_C = 100^\circ\text{C}$			1.0 2.5 5.0		V
$V_{BE(sat)}$	$I_B = 0.5 \text{ A}$ $I_B = 0.8 \text{ A}$ $I_B = 0.8 \text{ A}$	$I_C = 2.5 \text{ A}$ $I_C = 4 \text{ A}$ $I_C = 4 \text{ A}$	(see Notes 3 and 4) $T_C = 100^\circ\text{C}$			1.2 1.4 1.3		V
f_t	$V_{CE} = 10 \text{ V}$	$I_C = 0.5 \text{ A}$	$f = 1 \text{ MHz}$			12		MHz
C_{ob}	$V_{CB} = 20 \text{ V}$	$I_E = 0$	$f = 0.1 \text{ MHz}$			110		pF

NOTES: 2. Inductive loop switching measurement.

3. These parameters must be measured using pulse techniques, $t_p = 300 \mu\text{s}$, duty cycle $\leq 2\%$.

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance			1.25	°C/W

inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
t_{sv}	$I_C = 4 \text{ A}$ $V_{BE(off)} = -5 \text{ V}$	$I_{B(on)} = 0.8 \text{ A}$	(see Figures 1 and 2)			2.5	μs
t_{rv}						300	ns
t_{fi}						250	ns
t_{ti}						150	ns
t_{xo}						400	ns
t_{sv}	$I_C = 4 \text{ A}$ $V_{BE(off)} = -5 \text{ V}$	$I_{B(on)} = 0.8 \text{ A}$ $T_C = 100^\circ\text{C}$	(see Figures 1 and 2)			3	μs
t_{rv}						500	ns
t_{fi}						250	ns
t_{ti}						150	ns
t_{xo}						750	ns

† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

PRODUCT INFORMATION

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PARAMETER MEASUREMENT INFORMATION

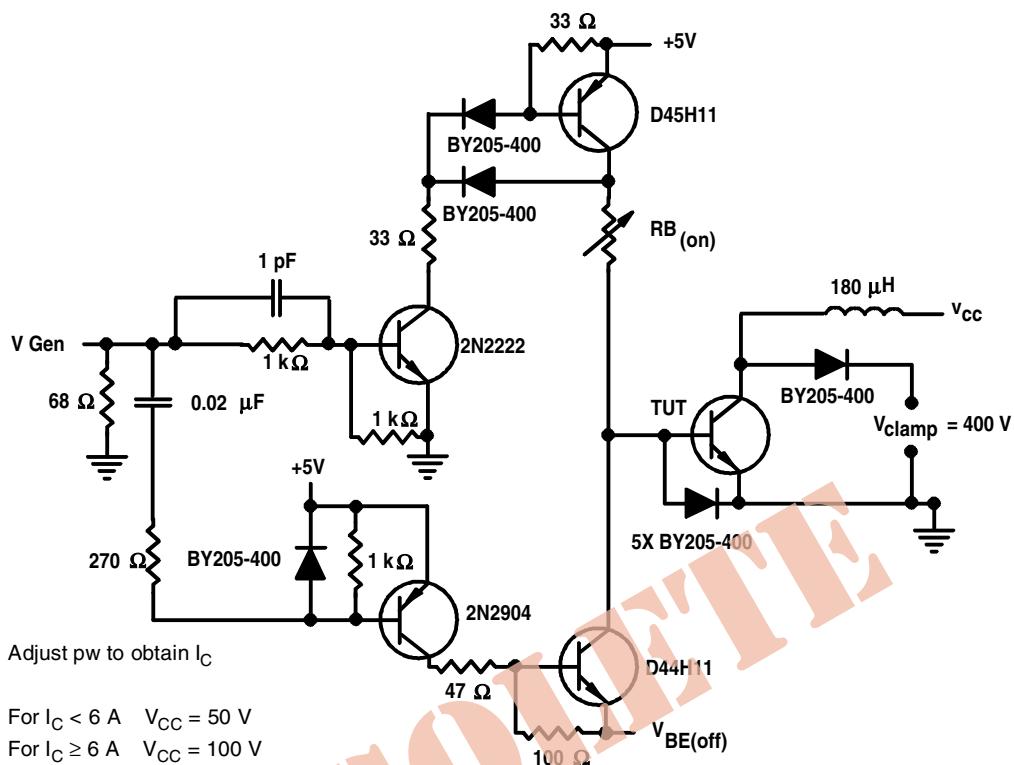
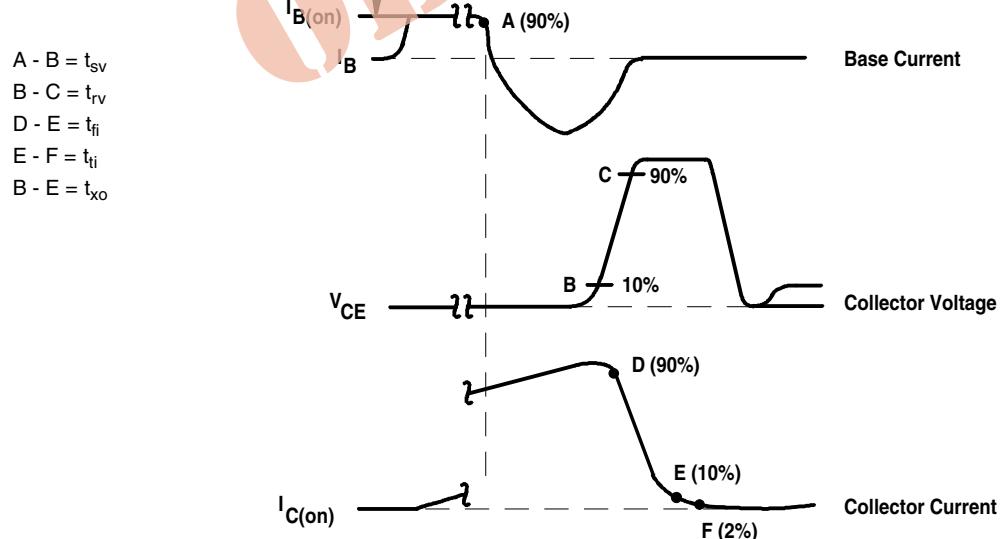


Figure 1. Inductive-Load Switching Test Circuit



NOTES: A. Waveforms are monitored on an oscilloscope with the following characteristics: $t_r < 15$ ns, $R_{in} > 10$ Ω, $C_{in} < 11.5$ pF.
 B. Resistors must be noninductive types.

Figure 2. Inductive-Load Switching Waveforms

PRODUCT INFORMATION

TYPICAL CHARACTERISTICS

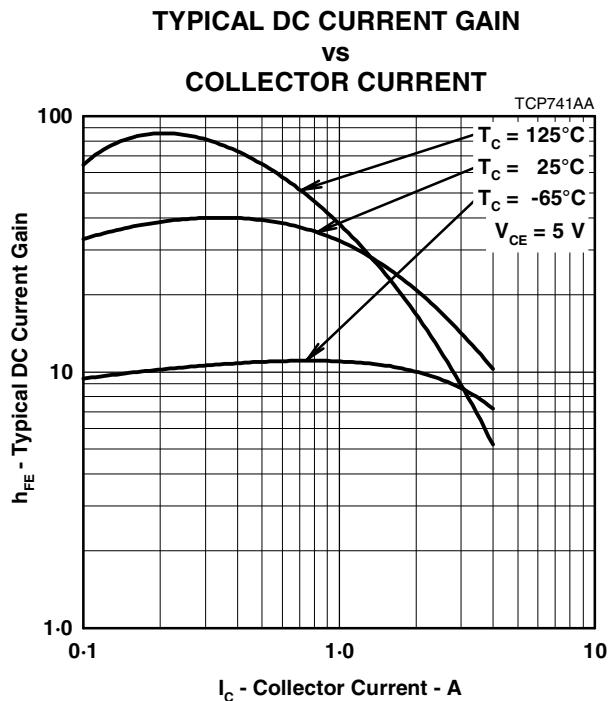


Figure 3.

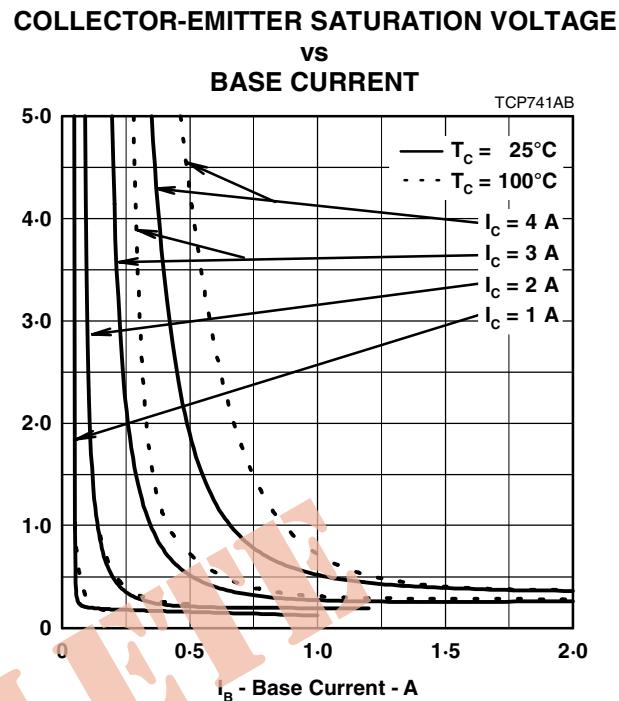


Figure 4.

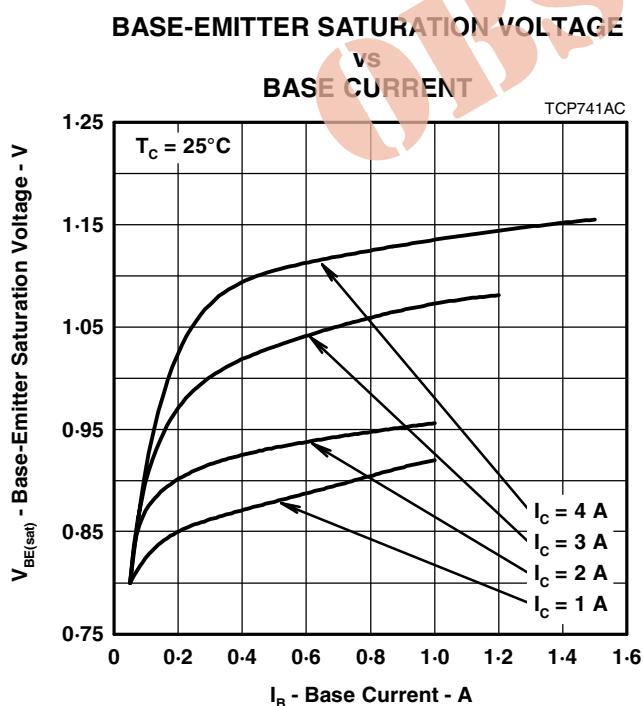


Figure 5.

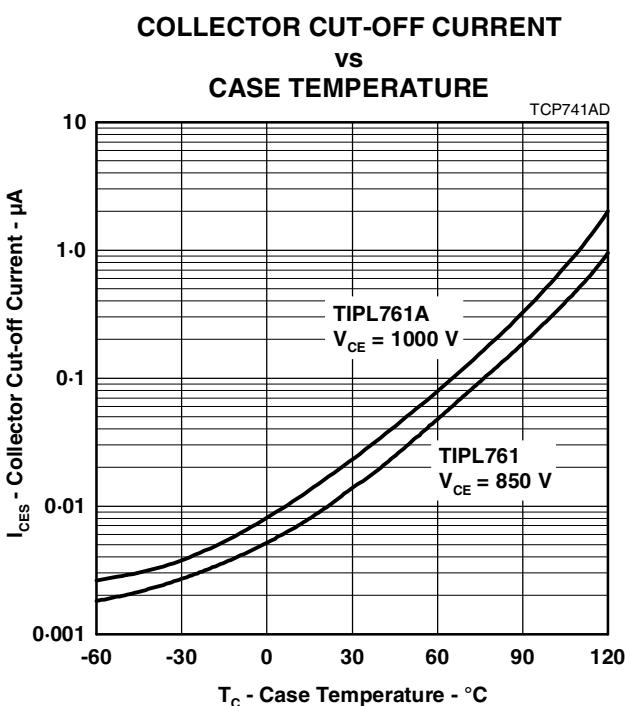


Figure 6.

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MAXIMUM SAFE OPERATING REGIONS

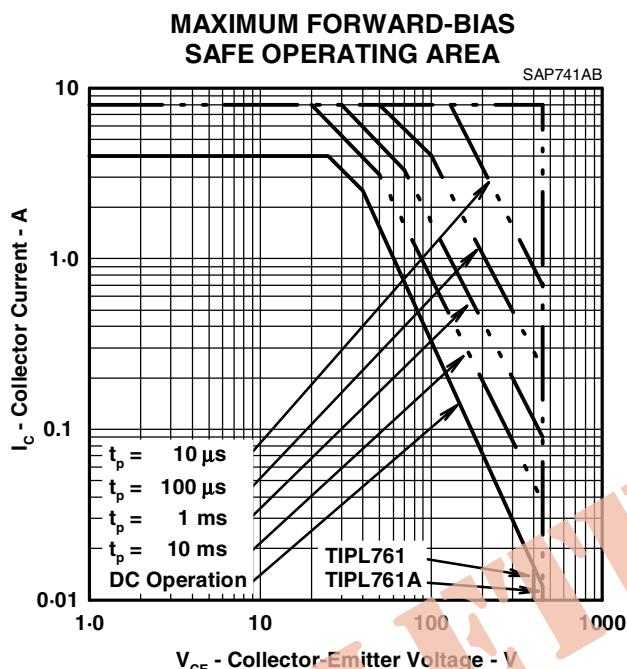


Figure 7.

THERMAL INFORMATION

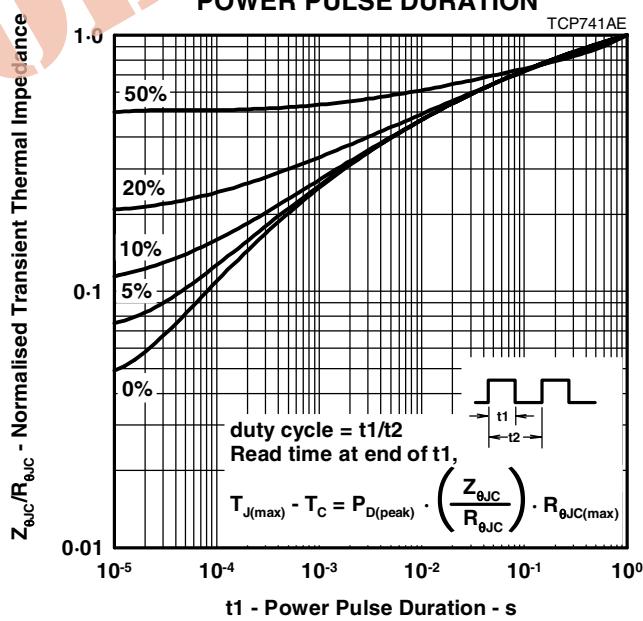
THERMAL RESPONSE JUNCTION TO CASE
vs
POWER PULSE DURATION

Figure 8.

PRODUCT INFORMATION